

20V N-Channel Enhancement Mode MOSFET

Voltage 20 V Current 4.1A

Features

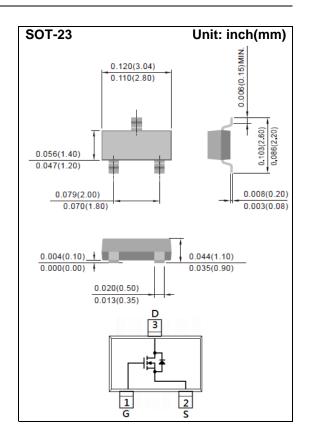
- R_{DS(ON)}, V_{GS}@4.5V, I_D@4.1A<56mΩ
- R_{DS(ON)}, V_{GS}@2.5V, I_D@2.8A<68mΩ
- $R_{DS(ON)}$, $V_{GS}@1.8V$, $I_{D}@1.5A<95m\Omega$
- Advanced Trench Process Technology
- Specially Designed for Switch Load, PWM Application, etc
- AEC-Q101 qualified
- Lead free in compliance with EU RoHS 2.0
- Green molding compound as per IEC 61249 standard

Mechanical Data

• Case: SOT-23 Package

• Terminals: Solderable per MIL-STD-750, Method 2026

• Approx. Weight: 0.0003 ounces, 0.0084 grams



Maximum Ratings and Thermal Characteristics (T_A=25°C unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS	
Drain-Source Voltage		V _{DS}	20	V	
Gate-Source Voltage	V _G s	<u>+</u> 12			
Continuous Drain Current		I _D	4.1	- A	
Pulsed Drain Current		I _{DM}	16.4		
Power Dissipation	T _a =25°C	P _D	1.25	W	
	Derate above 25°C		10	mW/°C	
Operating Junction and Storage Temperature Range		T _J ,T _{STG}	-55~150	°C	
Typical Thermal Resistance					
- Junction to Ambient (Note 3)		Reja	100	°C/W	



Electrical Characteristics (T_A=25°C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS	
Static							
Drain-Source Breakdown Voltage	BV _{DSS} V _{GS} =0V, I _D =250uA		20	-	-	V	
Gate Threshold Voltage	$V_{GS(th)}$	V _{DS} =V _{GS} , I _D =250uA	0.4	0.66	1.2	V	
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =4.5V, I _D =4.1A	-	41	56	mΩ	
		V _{GS} =2.5V, I _D =2.8A	-	50	68		
		V _{GS} =1.8V, I _D =1.5A	-	66	95		
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =20V, V _{GS} =0V	-	-	1	uA	
Gate-Source Leakage Current	I _{GSS}	V _{GS} = <u>+</u> 12V, V _{DS} =0V	-	-	<u>+</u> 100	nA	
Dynamic (Note 5)							
Total Gate Charge	Q_g	V _{DS} =10V, I _D =4.1A,	-	4.6	-	nC	
Gate-Source Charge	Qgs		-	0.8	-		
Gate-Drain Charge	Q_{gd}	V _{GS} =4.5V (Note 1,2)	-	1	-		
Input Capacitance	Ciss		-	350	-		
Output Capacitance	Coss	V _{DS} =10V, V _{GS} =0V, f=1.0MHZ	-	40	-	pF	
Reverse Transfer Capacitance	Crss	I=I.UIVIMZ	-	29	-		
Turn-On Delay Time	td _(on)	\/ 40\/ I 44A	-	4	-		
Turn-On Rise Time	tr	V _{DD} =10V, I _D =4.1A,	-	47	-	20	
Turn-Off Delay Time	td _(off)	$V_{GS}=4.5V$, $R_{G}=6\Omega$ (Note 1,2)	-	18	-	ns	
Turn-Off Fall Time	tf	RG=012 (1000 1,2)	-	10	-		
Drain-Source Diode							
Maximum Continuous Drain-Source	Is		-	-	1.5	А	
Diode Forward Current							
Diode Forward Voltage	V _{SD}	Is=1.0A, V _G s=0V	-	0.75	1.2	V	

NOTES:

- 1. Pulse width<a>300us, Duty cycle<a>2%.
- 2. Essentially independent of operating temperature typical characteristics.
- 3. R_{OJA} is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins mounted on a 1 inch FR-4 with 2oz. square pad of copper.
- 4. The maximum current rating is package limited.
- 5. Guaranteed by design, not subject to production testing.



TYPICAL CHARACTERISTIC CURVES

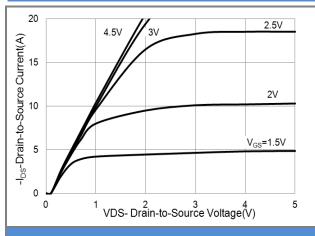


Fig.1 On-Region Characteristics

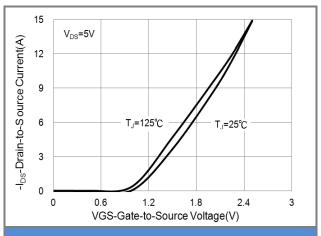


Fig.2 Transfer Characteristics

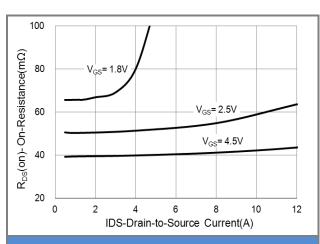


Fig.3 On-Resistance vs. Drain Current

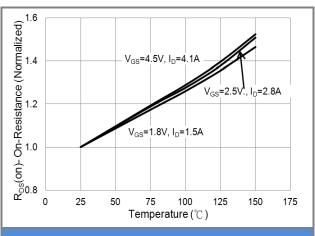
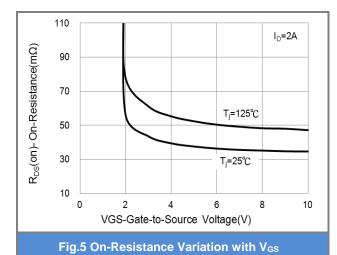
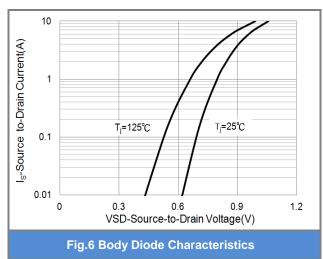


Fig.4 On-Resistance vs. Junction temperature







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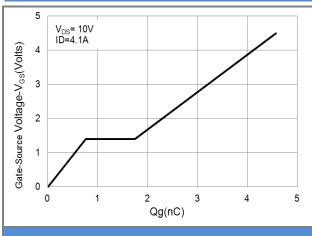


Fig.7 Gate-Charge Characteristics

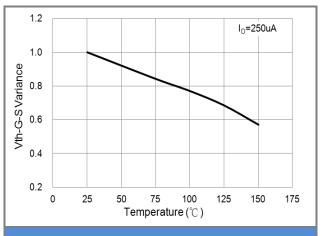


Fig.8 Threshold Voltage Variation with Temperature

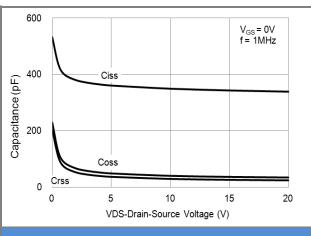


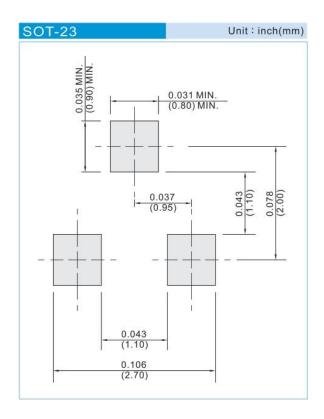
Fig.9 Capacitance vs. Drain-Source Voltage



Product and Packing Information

Part No.	Package Type	Packing Type	Marking	
PJA3412-AU	SOT-23	3K pcs / 7" reel	A12	

Mounting Pad Layout





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